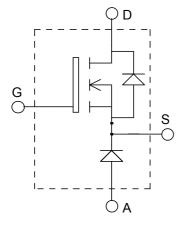


ISOTOP[®] Buck chopper MOSFET Power Module





$V_{DSS} = 200V$ $R_{DSon} = 22m\Omega \text{ max} @ Tj = 25^{\circ}C$ $I_D = 97A @ Tc = 25^{\circ}C$

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS V[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic diode
 - Avalanche energy rated
 - Very rugged
- ISOTOP[®] Package (SOT-227)
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Very rugged
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage			200	V
т	Continuous Drain Current $\frac{T_c = 25^{\circ}C}{T_c = 80^{\circ}C}$		97		
I _D			72	Α	
I _{DM}	Pulsed Drain current			388	
V _{GS}	Gate - Source Voltage			±30	V
R _{DSon}	Drain - Source ON Resistance			22	mΩ
P _D	Maximum Power Dissipation $T_c = 25^{\circ}C$			450	W
I _{AR}	Avalanche current (repetitive and non repetitive)			97	А
E _{AR}	Repetitive Avalanche Energy			50	mJ
E _{AS}	Single Pulse Avalanche Energy	2500	1115		
IF _{AV}	Maximum Average Forward Current	Duty cycle=0.5	$Tc = 90^{\circ}C$	30	А
IF _{RMS}	RMS Forward Current (Square wave, 50% duty)			47	A

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			25	μA
		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			250	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 48.5A$			22	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2.5 mA$	2		4	V
I _{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 V, V_{DS} = 0V$			±100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		8500		
Coss	Output Capacitance	$V_{\rm DS} = 25 V$		1950		pF
C _{rss}	Reverse Transfer Capacitance	f = 1 MHz		560		
Qg	Total gate Charge	$V_{GS} = 10V$		290		
Q _{gs}	Gate – Source Charge	$V_{Bus} = 100V$ $I_D = 97A @ T_J = 25^{\circ}C$		66		nC
Q_{gd}	Gate – Drain Charge			120		
T _{d(on)}	Turn-on Delay Time	$V_{GS} = 15V V_{Bus} = 100V I_D = 97A @ T_J = 25^{\circ}C R_G = 0.6\Omega$		16		
Tr	Rise Time			25		
T _{d(off)}	Turn-off Delay Time			48		ns
T_{f}	Fall Time			8		

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 30A$			1.1	1.15		
		$I_F = 60A$			1.4		V	
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		0.9			
I _{RM}	Maximum Reverse Leavage Lurrent	$V_{\rm R} = 200 {\rm V}$	$T_i = 25^{\circ}C$			250	μA	
1 KM		$V_{\rm R} = 200 {\rm V}$	$T_{i} = 125^{\circ}C$			500		
CT	Junction Capacitance	$V_{\rm R} = 200 {\rm V}$			94		pF	
£	Reverse Recovery Time	$I_F=1A, V_R=30V$ di/dt=200A/µs	$T_j = 25^{\circ}C$		21		ns A	
t _{rr}	Reverse Recovery Time	$I_F = 30A$ $V_R = 133V$ $di/dt = 200A/\mu s$	$T_i = 25^{\circ}C$		24			
			$T_{i} = 125^{\circ}C$		48			
I _{RRM}	Maximum Reverse Recovery Current		$T_j = 25^{\circ}C$		3			
1 KKM			$T_{i} = 125^{\circ}C$		6			
0	Reverse Recovery Charge		$T_j = 25^{\circ}C$		33		nC	
Q _{rr}			$T_j = 125^{\circ}C$		150		lic	
t _{rr}	Reverse Recovery Time	$I_F = 30A$ $V_R = 133V$ $di/dt = 1000A/\mu s$			31		ns	
Qrr	Reverse Recovery Charge		$T_j = 125^{\circ}C$		335		nC	
I _{RRM}	Maximum Reverse Recovery Current				19		Α	

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2 - 8

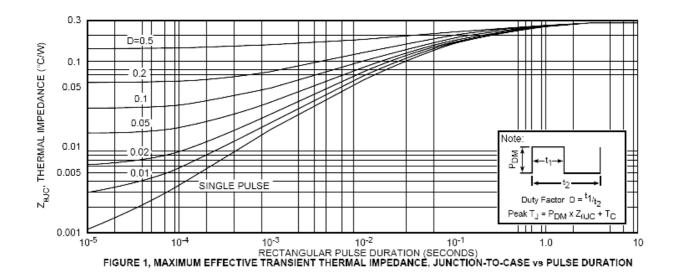


Thermal and package characteristics

Symbol	Characteristi	с

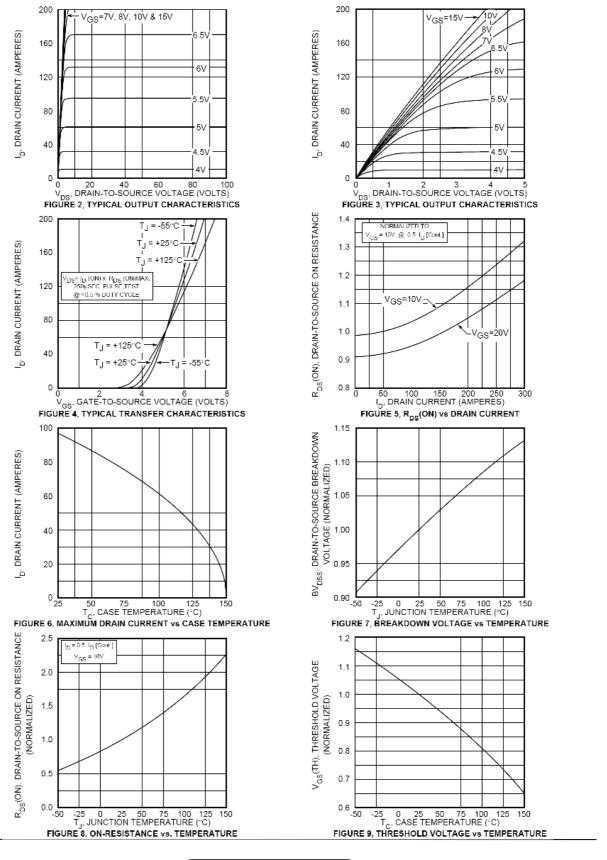
Symbol	Characteristic		Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance MOSFET Diode	MOSFET			0.28	
		Diode			1.21	°C/W
R _{thJA}	Junction to Ambient (IGBT & Diode)				20	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		2500			V
T_J, T_{STG}	Storage Temperature Range		-55		150	°C
T _L	Max Lead Temp for Soldering:0.063" from case for 10 sec				300	C
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m
Wt	Package Weight			29.2		g

Typical MOSFET Performance Curve



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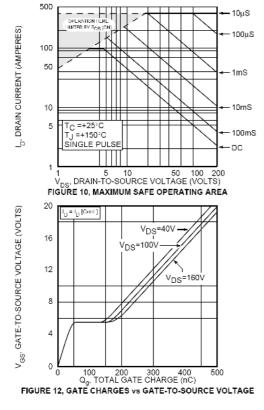


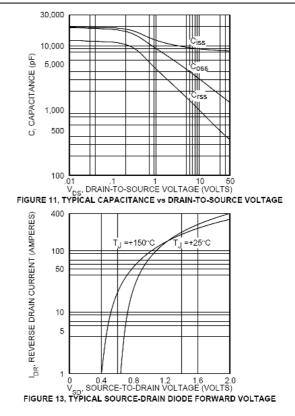
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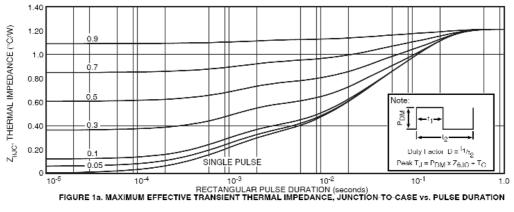
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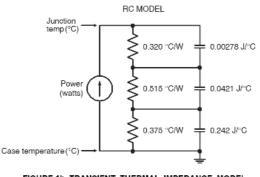
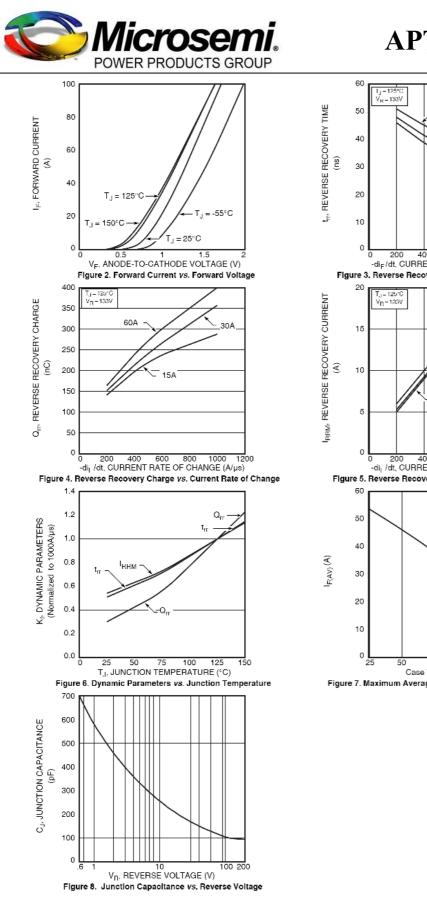
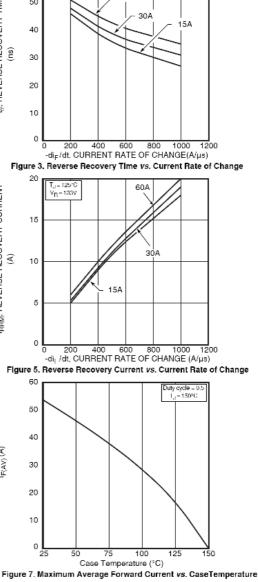


FIGURE 1b, TRANSIENT THERMAL IMPEDANCE MODEL



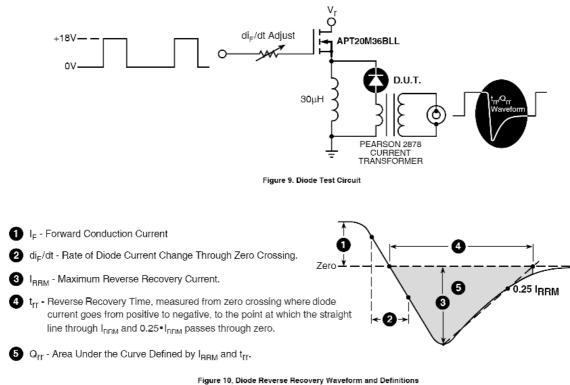


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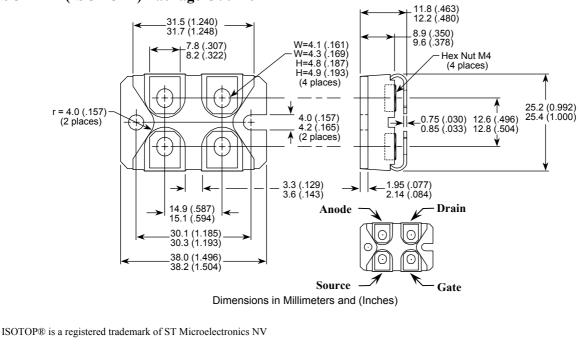
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SOT-227 (ISOTOP[®]) Package Outline



APT20M22JVRU3-Rev 2 October 2012



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